Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

4.2 millimeters

Terminal Length:

26.0 millimeters

Overall Diameter:

1.0 millimeters

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

35.0 reverse voltage, peak and 30.0 reverse voltage, instantaneous

Current Rating Per Characteristic:

360.00 milliamperes source cutoff current peak and 120.00 milliamperes forward current, average absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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